

General Description

The AL8841QEV1-EMC, shown in Figure 1, is a doublesided evaluation board for the AL8841Q step-down, or "buck", LED driver with internal switch in the TSOT25 package. The evaluation board is preset to drive 1000mA into a single LED or multiple LEDs, the maximum number of which depends on their total forward voltage drop and the supply voltage.

This guide contains rich information for users to take advantage of. A bill of materials that describes the parts used on this board is included. A schematic and PCB layout are also included, along with measured system performance characteristics and test waveforms. These materials can be used as a reference design for your products to improve time to market.

Key Features

- AEC-Q100 Grade 1 Qualified
- Wide Input Voltage Range: 5V to 40V
- Constant Current Mode PWM Controller
- PWM/Analog Dimming Mode
- Up to 1MHz Switching Frequency
- Built-in Comprehensive Protections
 - Undervoltage Lock Out (UVLO)
 - Overvoltage Protection(OVP)
 - Overcurrent Protection(OCP)
 - Overtemperature Protection (OTP)
 - LED Open Protection
 - Output Short Protection
- Low System BOM Cost
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- The AL8841Q is suitable for automotive applications requiring specific change control; this part is AEC-Q100 qualified, PPAP capable, and manufactured in IATF 16949 certified facilities.

https://www.diodes.com/guality/product-definitions/

Applications

- Head up displays (HUD)
- Auto backlight displays

Specifications

Parameter	Value
Input Voltage	5V~40Vdc
Output Current	1A
Output Voltage	1~10LEDs
Efficiency	>82%
Dimension	74mm*46mm*10mm
RoHS Compliance	Yes

1. No purposely added lead. FullyEU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ formore information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



AL8841QEV1-EMC User Guide

High-Performance Buck 1A Demo Board

Evaluation Board

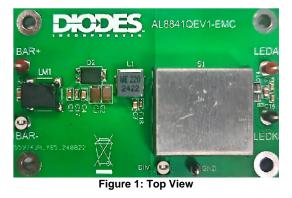




Figure 2: Bottom View

Connection Instructions

DC Positive Input: Red Test Point (BAR+) DC Negative Input: White Test Point (BAR-) PWM Signal Input: White Test Point (DIM) GND Signal Input: Black Test Point (GND) Positive Output: Red Test Point (LEDA) Negative Output: Black Test Point (LEDK)



Board Layout

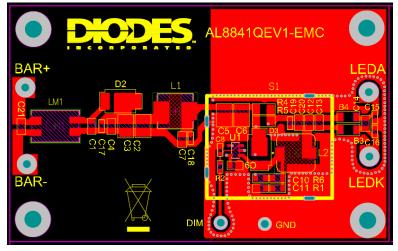


Figure 3: PCB Layout Top View

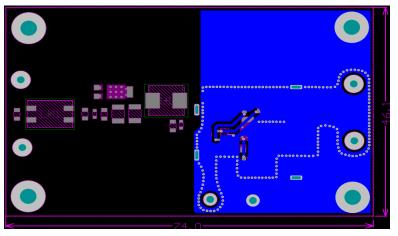


Figure 4: PCB Layout Bottom View



Quick Start Guide

- 1. Ensure that the power supply and the PWM signal are switched OFF or disconnected.
- 2. Connect the LED power supply to the test point "BAR+" and "BAR-".
- 3. Connect the LED string anode to the test point "LEDA".
- 4. Connect the LED string cathode to the test point "LEDK".
- 5. Turn on the LED power supply. The LED string will light on and output the preset current.
- 6. Dimming mode: Connect the PWM/Analog signal to "DIM" and "GND".

Evaluation Board Schematic

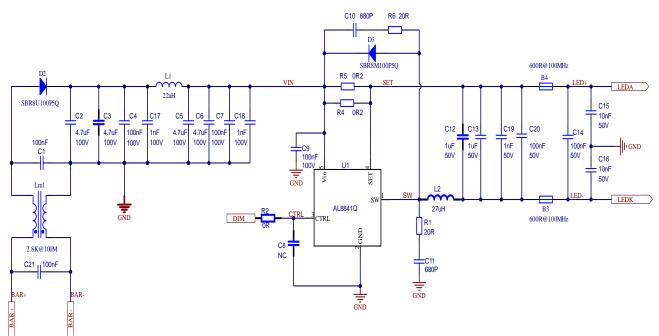


Figure 5: Schematic Circuit



AL8841QEV1-EMC User Guide

High-Performance Buck 1A Demo Board

Bill of Materials

NO.	Location	Description	Package	Quantity
1	R2	Resistor, SMT, 0 ohm, 0603, 5%	0603	1
2	R4, R5	Resistor, SMT, 0.2 ohm, 1206, 1%	1206	2
3	R1, R6	Resistor, SMT, 20 ohm, 0805, 5%	0805	2
4	C2, C3, C5, C6	Cap, Cer, GCJ32DC72A475KE01L, 4.7uF, 100V, X7S, 1210, -55°C~125°C, AEC-Q200, Murata	1210	4
5	C1, C4, C7, C9, C21	Cap, Cer, CGA4J2X7R2A104K125AA, 100nF,100V,X7R, 0805, -55°C~125°C, AEC-Q200,TDK	0805	5
6	C15, C16	Cap, Cer, CGA3E2X7R2A103K080AA, 10nF, 100V, X7R, 0603, -55°C~125°C, AEC-Q200, TDK	0603	2
7	C17, C18	Cap, Cer, CGA3E2X7R2A102K080AA, 1nF, 100V, X7R, 0603, -55°C~125°C, AEC-Q200, TDK	0603	2
8	C10, C11	Cap, Cer, CL21C681JCC1PNC, 680pF, 100V, NP0, 0805, -55°C~125°C, AEC-Q200, Samsung	0805	2
9	C12, C13	Cap, Cer, CGA4J3X7R1H105K125AB, 1uF, 50V, X7R, 0805, -55°C~125°C, AEC-Q200, TDK	0805	2
10	C14, C20	Cap, Cer, CGA4J2X8R1H104K125AA, 100nF, 50V, X8R, 0805, -55°C~150°C, AEC-Q200, TDK	0805	2
11	C19	Cap, Cer, GCD188R71H102KA01D, 1nF, 50V, X7R, 0603, -55°C~125°C, AEC-Q200, Murata	0603	1
12	U1	IC, AL8841QWT-7, AEC-Q100 Qualified, DIODES	TSOT25	1
13	B3, B4	78279221601, 600ohm@100MHz, AEC-Q200, Würth Elektronik	1206	2
14	L1	74437349220, 22uH, Isat=2.1A,7.3x6.6x4.8mm, AEC-Q200, Würth Elektronik	SMT	1
15	L2	7447779127,27uH, Isat=1.24A, 7.3x7.3x4.5mm, AEC-Q200, Würth Elektronik	SMT	1
16	LM1	744228,CM 25uH,1000mA,2.8K@100MHz,AEC-Q200, Würth Elektronik	SMT	1
17	D2, D3	Diode, SBR8M100P5Q-13,8A,100V, AEC-Q101 Qualified, DIODES	POWER DI5	2
18	DIM	Connector, Orange color	DIP	1
19	LEDK, GND	Connector, Black color	DIP	2
20	BAR-	Connector, White color	DIP	1
21	LEDA, BAR+	Connector, Red color	DIP	2
22	S1	Shielding cover (IFG-2024) 20mmx24.5mmx10mm	DIP	1



System Performance

The AL8841Q evaluation board has excellent system performance. With a very low BOM cost, the system can achieve high efficiency and good dimming linearity. To enhance reliability, the AL8841Q also integrates comprehensive protections.

System Efficiency

Figure 6 shows the efficiency curve, which is measured with 12V DC input and 2*LED as the load.

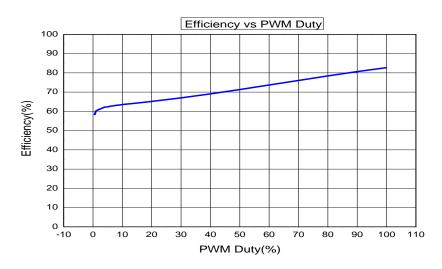


Figure 6: Efficiency vs PWM Duty

System Line Regulation

Figure 7 shows the line regulation, which is measured with 12~40V DC input and 2*LED as the load.

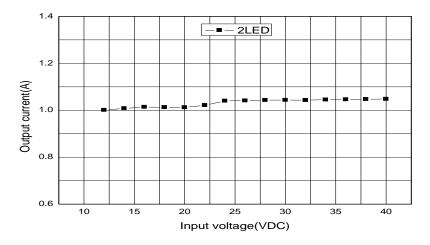


Figure 7: Efficiency vs PWM Duty



Dimming Performance

The AL8841Q supports PWM dimming with frequencies ranging from 100Hz to 20 kHz. Figure 8 shows the dimming curve with measured data. The AL8841Q dimming linearity is good, with PWM duty from 1% to 100%.

Figure 8: LED Current vs PWM Duty

Figure 9: LED Current vs DIM Pin Voltage



LED Open Protection

The AL8841Q has, by default, open LED protection. If the LEDs should become open in the circuit, the AL8841Q will stop oscillating; the SET pin will rise to VIN and the SW pin will then fall to GND. No excessive voltages will be seen by the AL8841Q.

Figure 10 illustrates the LED open protection procedure. In the waveform, channel 1 (**yellow**) is the GATE signal, channel 2 (**red**) is the CTRL signal, channel 3 (**blue**) is the LED-, and channel 4 (**green**) is the LED current. If the LED is open, the system operates in a low-current state. If the LED is connected, the system will resume normal operation.

Figure 10: LED Open Protection with 100% Duty

LED Short Protection

When the LED chain should become shorted together (the anode of the top LED becomes shorted to the cathode of the bottom LED) the AL8841Q will continue to switch and the current through the AL8841Q's internal switch will still be at the expected current. Thus, no excessive heat will be generated within the AL8841Q.

Figure 11 depicts the LED short protection procedure. In the waveforms, channel 1 (**yellow**) is the GATE signal, channel 2 (**red**) is the CTRL signal, channel 3 (**blue**) is the LED-, and channel 4 (**green**) the LED current. When the LED short circuits, the on-time of the internal power MOSFET switch is significantly reduced because almost all of the input voltage is now developed across the inductor. The off-time is significantly increased because the reverse voltage across the inductor is now the Schottky diode voltage, causing a much slower decay in inductor current.



AL8841QEV1-EMC User Guide

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LED Short Protection (continued)

Figure 11: LED Short Circuit Protection with 100% Duty

Thermal Test

Test condition: V_{IN}= 12V, V_{O}=6.6V (2LEDs), Ta=26.6 $^\circ \! \mathbb C$

Vin(V)	lin(A)	Vout(V)	lout(A)	Efficiency (%)	Power Inductor Temp(°C)	Diode Temp(°C)	IC Temp(°C)
12	0.6407	6.3323	1.00435	82.5	50.7	52.1	61.2



Conductive Emission Test

Test condition: VIN = 12V, VO = 6.6V (2LEDs)

1. CE+_0.15-28MHz CISPR 25 Class 5_Pass_5.24dB Margin

Frequency	MaxPeak	Average	Limit	Margin	Line	Corr.
MHz	dBµV	dBµV	dBµV	dB		dB
31.300000		14.08	24.00	9.92	Single Line	0.9
43.750000	16.36		34.00	17.64	Single Line	1.1
45.450000	16.10		34.00	17.90	Single Line	1.1
75.450000		7.89	18.00	10.11	Single Line	1.6
87.300000	17.21		34.00	16.79	Single Line	1.8
99.900000		11.08	18.00	6.92	Single Line	2.0
106.750000		12.76	18.00	5.24	Single Line	2.1



Conductive Emission Test (continued)

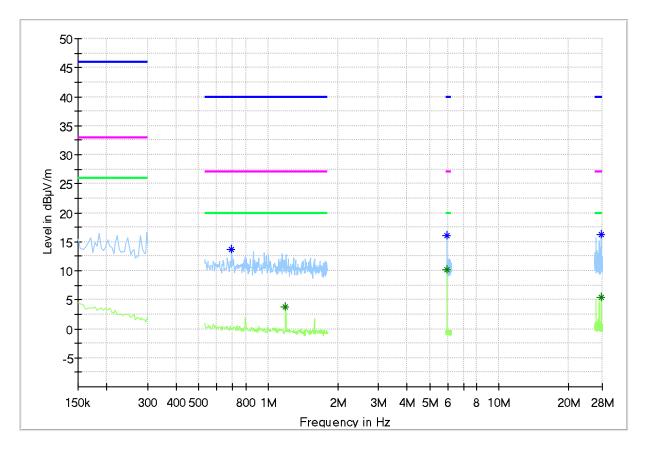
2. CE-_0.15-108MHz CISPR 25 Class 5_Pass_4.35dB Margin

Frequency	MaxPeak	Average	Limit	Margin	Line	Corr.
MHz	dBµV	dBµV	dBµV	dB		dB
26.084000		9.40	24.00	14.60	Single Line	0.8
27.796000	15.43		44.00	28.57	Single Line	0.8
30.360000		13.07	24.00	10.93	Single Line	0.8
44.920000	15.37		34.00	18.63	Single Line	1.0
87.280000	17.53		34.00	16.47	Single Line	1.8
106.960000		13.65	18.00	4.35	Single Line	2.0



Conductive Emission Test (continued)

3. RE_0.15-28M CISPR 25 Class 5_Pass_9.73dB Margin

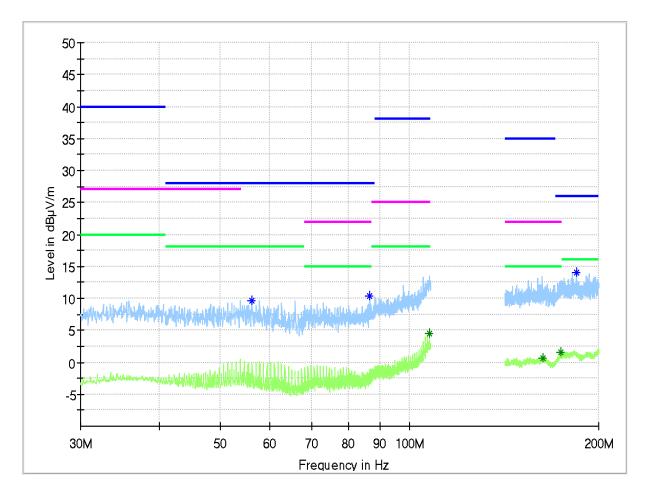


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m
0.694000	13.76		40.00	26.24			V	10.0
1.190000		3.68	20.00	16.32			V	10.0
5.956000	16.12		40.00	23.88			V	10.2
5.956000		10.27	20.00	9.73			V	10.2
27.804000		5.49	20.00	14.51			V	10.3
27.804000	16.15		40.00	23.85			V	10.3



Conductive Emission Test (continued)

4. RE_30-200M_ Horizontal _CISPR 25 Class 5_Pass_11.92dB Margin

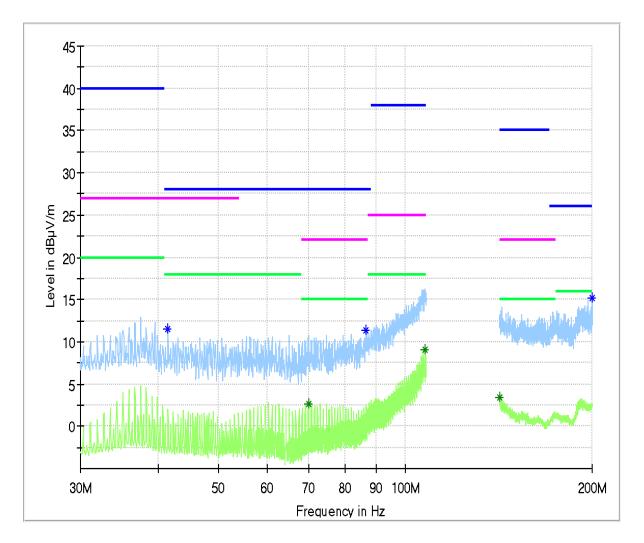


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m
56.100000	9.63		28.00	18.37			Н	-14.6
86.600000	10.44		28.00	17.56			Н	-14.6
107.650000		4.55	18.00	13.45			Н	-13.2
163.000000		0.71	15.00	14.29			Н	-10.4
174.200000		1.47	15.00	13.53			Н	-9.9
184.150000	14.08		26.00	11.92			Н	-9.8



Conductive Emission Test (continued)

5. RE_30-200M_ Vertical _CISPR 25 Class 5_Pass_8.97dB Margin

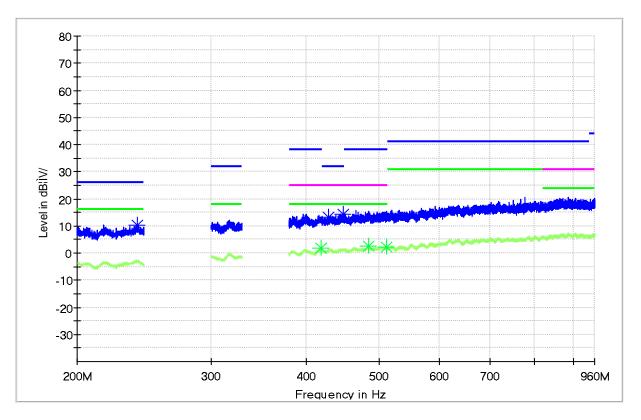


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m
41.500000	11.58		28.00	16.42			V	-13.2
69.850000		2.68	15.00	12.32			V	-15.4
86.600000	11.41		28.00	16.59			V	-14.6
107.800000		9.03	18.00	8.97			V	-13.2
142.050000		3.40	15.00	11.60			V	-11.3
199.900000	15.13		26.00	10.87			V	-8.7



Conductive Emission Test (continued)

6. RE_200-960M_ Horizontal _CISPR 25 Class 5_Pass_18dB Margin

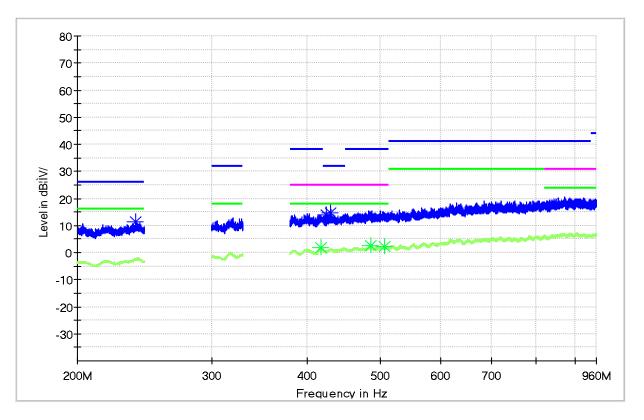


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.	Comment
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m	
240.100000	10.31		26.00	15.69			Н	-12.5	11:22:34 - 2024/10/31
418.400000		1.68	18.00	16.32			Н	-7.6	11:22:35 - 2024/10/31
427.950000	13.25		32.00	18.75			Н	-8.0	11:22:34 - 2024/10/31
448.400000	14.41		32.00	17.59			Н	-7.1	11:22:34 - 2024/10/31
483.400000		2.40	18.00	15.60			Н	-6.6	11:22:35 - 2024/10/31
510.650000		2.32	18.00	15.68			Н	-6.8	11:22:35 - 2024/10/31



Conductive Emission Test (continued)

7. RE_200-960M Vertical _CISPR 25 Class 5_Pass_14.72dB Margin

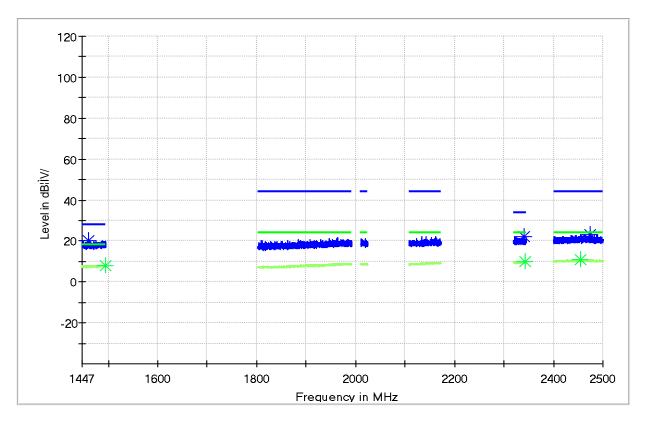


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.	Comment
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m	
238.400000	11.28		26.00	14.72			V	-12.4	11:30:12 - 2024/10/31
417.950000		1.75	18.00	16.25			V	-7.6	11:30:12 - 2024/10/31
424.300000	13.86		32.00	18.14			V	-8.1	11:30:12 - 2024/10/31
430.400000	14.75		32.00	17.25			V	-7.6	11:30:12 - 2024/10/31
484.800000		2.54	18.00	15.46			V	-6.6	11:30:12 - 2024/10/31
505.300000		2.38	18.00	15.62			V	-6.7	11:30:12 - 2024/10/31



Conductive Emission Test (continued)

8. RE_200-960M Horizontal _CISPR 25 Class 5_Pass_7.59dB Margin

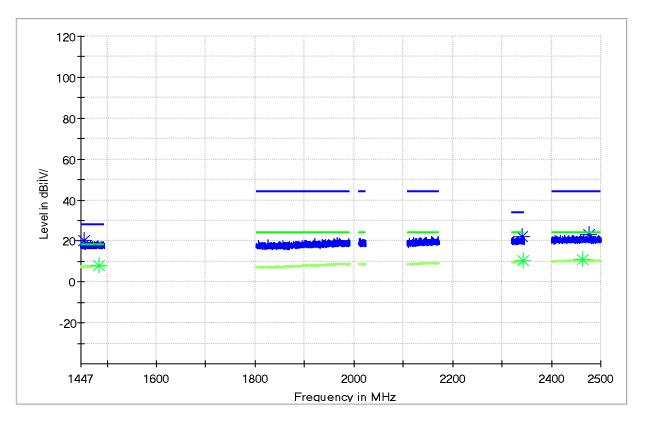


Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.	Comment
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m	
1460.250000	20.41		28.00	7.59	5.0	120.000	Н	-12.0	13:26:59 - 2024/10/31
1493.500000		8.07	18.00	9.93	5.0	120.000	Н	-12.0	13:26:59 - 2024/10/31
2341.550000	22.30		34.00	11.70	5.0	120.000	Н	-9.4	13:26:59 - 2024/10/31
2343.450000		10.11	24.00	13.89	5.0	120.000	Н	-9.3	13:26:59 - 2024/10/31
2455.200000		10.96	24.00	13.04	5.0	120.000	Н	-8.6	13:26:59 - 2024/10/31
2473.100000	23.05		44.00	20.95	5.0	120.000	Н	-8.6	13:26:59 - 2024/10/31



Conductive Emission Test (continued)

9. RE_200-960M Vertical _CISPR 25 Class 5_Pass_7.83dB Margin



Frequency	MaxPeak	Average	Limit	Margin	MeasTime	Bandwidth	Pol	Corr.	Comment
MHz	dBµV/m	dBµV/m	dBµV/m	dB	ms	kHz		dB/m	
1453.450000	20.17		28.00	7.83	5.0	120.000	V	-12.0	13:29:35 - 2024/10/31
1484.550000		8.19	18.00	9.81	5.0	120.000	V	-12.0	13:29:35 - 2024/10/31
2341.250000	21.97		34.00	12.03	5.0	120.000	V	-9.4	13:29:35 - 2024/10/31
2343.550000		10.27	24.00	13.73	5.0	120.000	V	-9.3	13:29:35 - 2024/10/31
2462.650000		11.04	24.00	12.96	5.0	120.000	V	-8.6	13:29:35 - 2024/10/31
2476.250000	23.19		44.00	20.81	5.0	120.000	V	-8.6	13:29:35 - 2024/10/31



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